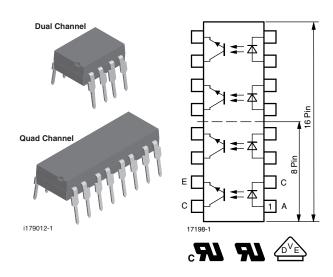


Vishay Semiconductors

Optocoupler, Phototransistor Output, (Dual, Quad Channel)



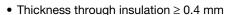
DESCRIPTION

The TCET2100/TCET4100 consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode, available in 8 pin (dual channel) and 16 pin (quad channel) package.

FEATURES

- Extra low coupling capacity typical 0.2 pF
- High common mode rejection
- Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage)
 V_{IOTM} = 10 kV peak





 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO

ORDERING INFORMATI	ON				
ТС	T # 1 0 0	DIP			
	PART NUMBER	7.62 mm			
AGENCY CERTIFIED/PACKAGE	CTR (%)				
UL, cUL, VDE	50 to 600				
DIP-8, dual channel	TCET2100				
DIP-16, quad channel	TCET4100				

TCET2100, TCET4100



Vishay Semiconductors Optocoupler, Phototransistor Output, (Dual, Quad Channel)

ABSOLUTE MAXIMUM RATINGS (1) (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V_R	6	V			
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α			
Power dissipation		P _{diss}	100	mW			
Junction temperature		T _j	125	°C			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		T _j	125	°C			
COUPLER							
Isolation test voltage (RMS)	t = 1 s	V _{ISO}	5300	V_{RMS}			
Isolation voltage		V _{IORM}	890	V_{P}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	- 55 to + 100	°C			
Storage temperature range		T _{stg}	- 55 to + 150	°C			
Soldering temperature (2)	2 mm from case, t ≤ 10 s	T _{sld}	260	°C			

Notes

⁽²⁾ Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	$I_F = \pm 50 \text{ mA}$	V _F		1.25	1.6	V	
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j		50		pF	
OUTPUT							
Collector emitter voltage	I _C = 1 mA	V _{CEO}	70			V	
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V	
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}		10	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}			0.3	V	
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		110		kHz	
Coupling capacitance	f = 1 MHz	C _k		0.3		pF	

Note

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
I _C /I _F	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	CTR	50		600	%	

⁽¹⁾ Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.



Optocoupler, Phototransistor Output, Vishay Semiconductors (Dual, Quad Channel)

MAXIMUM SAFETY RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward current		I _F			275	mA	
OUTPUT							
Power dissipation		P _{diss}			400	mW	
COUPLER							
Rated impulse voltage		V _{IOTM}			10	kV	
Safety temperature		T _{si}			175	°C	

Note

According to DIN EN 60747-5-5 (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings.
 Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	1.669			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	V_{IOTM}	10			kV
		V_{pd}	1.424			kV
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω

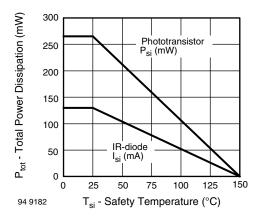


Fig. 1 - Derating Diagram

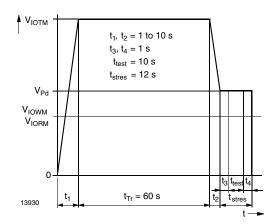


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC60747



Vishay Semiconductors Optocoupler, Phototransistor Output, (Dual, Quad Channel)

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, \ I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega,$ (see figure 3)	t _d		3		μs	
Rise time	$V_S = 5 \text{ V}, \ I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega,$ (see figure 3)	t _r		3		μs	
Turn-on time	$V_S = 5 \text{ V}, \ I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega,$ (see figure 3)	t _{on}		6		μs	
Storage time	$V_S = 5 \text{ V}, \ I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega,$ (see figure 3)	t _s		0.3		μs	
Fall time	$V_S = 5 \text{ V}, \ I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega,$ (see figure 3)	t _f		4.7		μs	
Turn-off time	$V_S = 5 \text{ V}, \ I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega,$ (see figure 3)	t _{off}		5		μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{on}		9		μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{off}		10		μs	

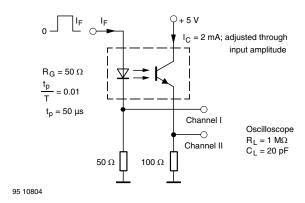


Fig. 3 - Test Circuit, Non-Saturated Operation

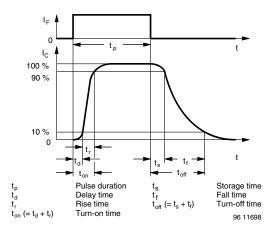


Fig. 5 - Switching Times

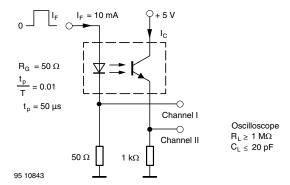


Fig. 4 - Test Circuit, Saturated Operation



Optocoupler, Phototransistor Output, Vishay Semiconductors (Dual, Quad Channel)

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

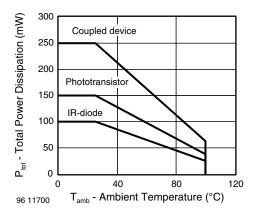


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

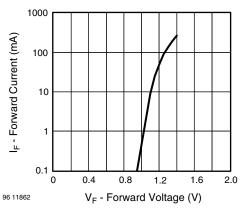


Fig. 7 - Forward Current vs. Forward Voltage

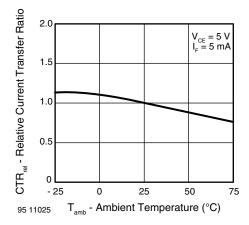


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

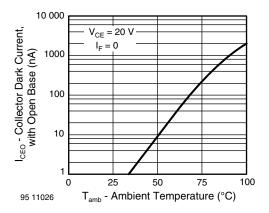


Fig. 9 - Collector Dark Current vs. Ambient Temperature

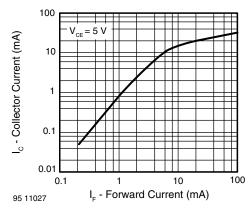


Fig. 10 - Collector Current vs. Forward Current

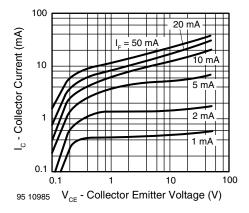


Fig. 11 - Collector Current vs. Collector Emitter Voltage

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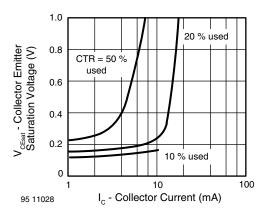


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

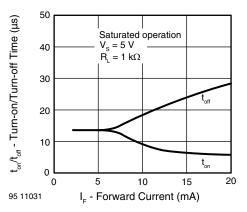


Fig. 15 - Turn-on/off Time vs. Forward Current

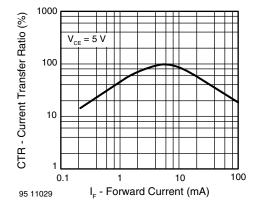


Fig. 13 - Current Transfer Ratio vs. Forward Current

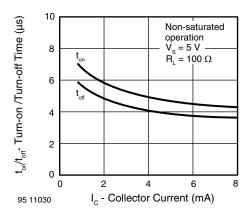
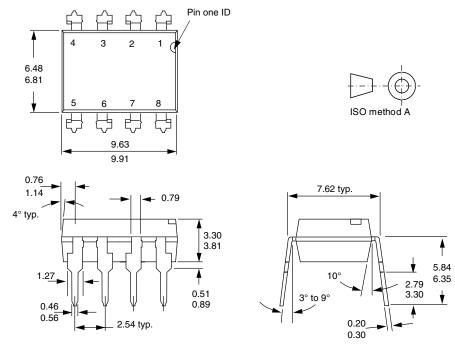


Fig. 14 - Turn-on/off Time vs. Collector Current

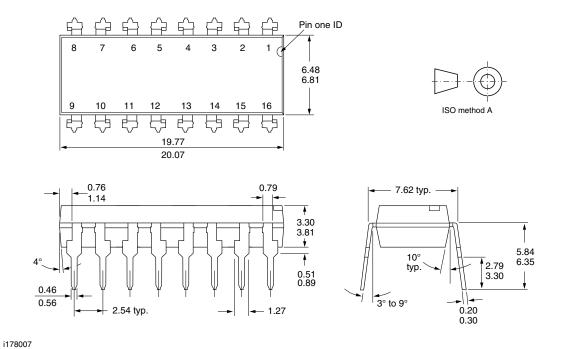


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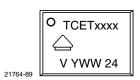
PACKAGE DIMENSIONS in millimeters



i178006



PACKAGE MARKING





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